



SI1029X-T1-GE3 Information



For Reference Only

Part Number SI1029X-T1-GE3
Manufacturer Vishay Siliconix

Category Discrete Semiconductor Products
Transistors - FETs, MOSFETs - Arrays

Description MOSFET N/P-CH 60V SC89-6

Package SOT-563, SOT-666

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









SI1029X-T1-GE3 Specifications

Manufacturer Part Number	SI1029X-T1-GE3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Arrays
Package	SOT-563, SOT-666
Series	TrenchFET?
FET Type	N and P-Channel
FET Feature	Logic Level Gate
Drain to Source Voltage (Vdss)	60V
Current - Continuous Drain (Id) @ 25°C	305mA, 190mA
Rds On (Max) @ Id, Vgs	1.4 Ohm @ 500mA, 10V
Vgs(th) (Max) @ Id	2.5V @ 250μA
Gate Charge (Qg) (Max) @ Vgs	0.75nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	30pF @ 25V
Power - Max	250mW
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	SOT-563, SOT-666
Supplier Device Package	SC-89-6
	Report errors?

SI1029X-T1-GE3 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

SI1029X-T1-GE3 Payment Methods



















SI1029X-T1-GE3 Shipping Methods













If you have any question about SI1029X-T1-GE3, please do not hesitate to contact us!

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